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ROHS

HALOGEN FREE

# Hyperfast Rectifier, 60 A FRED Pt® G5



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> per leg	60 A				
$V_{R}$	600 V				
V <sub>F</sub> at I <sub>F</sub> at 125 °C	1.2 V				
t <sub>rr</sub> (typ.)	29				
I <sub>FSM</sub>	500				
T <sub>J</sub> max.	175 °C				
Package	TO-247AD 2L				
Circuit configuration	Single				

#### **FEATURES**

- Hyperfast and optimized Q<sub>rr</sub>
- Best in class forward voltage drop and switching losses trade off



- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	$V_{RRM}$		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 110 °C, D = 0.50	60				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	500	Α			
Repetitive peak forward current	I <sub>FRM</sub>	$T_C = 110 ^{\circ}\text{C},  D = 0.50,  f = 20  \text{kHz}$	120				
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.4	1.7	V		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.2	-			
Deverage legisage grownst	I <sub>R</sub>	$V_R = V_R$ rated	-	-	25			
Reverse leakage current		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	65	-	pF		
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH		



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		29	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	49	-	ns	
		T <sub>J</sub> = 125 °C		-	74	-		
Dook rooms ourrent		T <sub>J</sub> = 25 °C	$I_F = 40 \text{ A}$ $dI_F/dt = 1000 \text{ A/µs}$ $V_R = 400 \text{ V}$	-	21	-	А	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	43	-		
Daylerge receivery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	640	-	nC	
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	1979	-		
Deverse vecesies time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	$I_F = 60 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	54	-	ns	
Reverse recovery time		T <sub>J</sub> = 125 °C		-	82	-		
Deals received a surrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	22	-	А	
Peak recovery current		T <sub>J</sub> = 125 °C		-	47	-		
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	790	-	nC	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	1	-	2385	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	0.63	°C/W		
Weight			-	5.5	-	g		
Weight			-	0.2	-	oz.		
Mounting torque			6 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Marking device		Case style TO-247AD 2L	E5PH6006L					

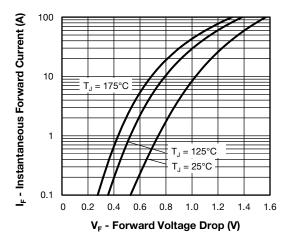


Fig. 1 - Typical Forward Voltage Drop Characteristics

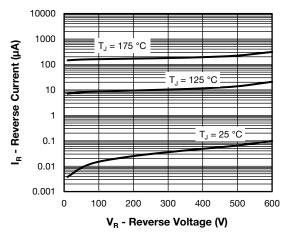


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

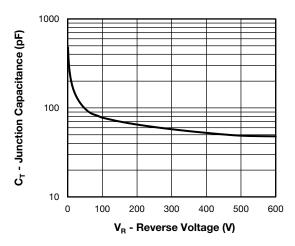


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

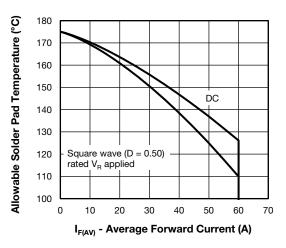


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

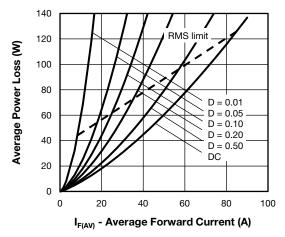


Fig. 5 - Average Power Loss vs. Average Forward Current

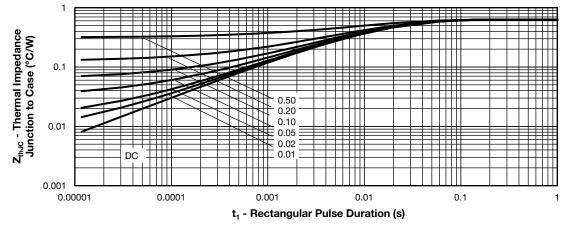


Fig. 6 - Thermal Impedance  $Z_{thJC}$  Characteristics

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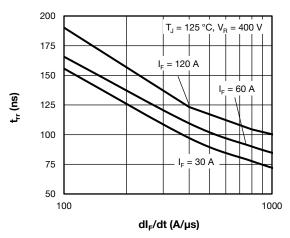


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

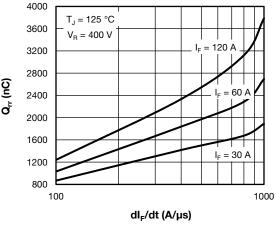


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

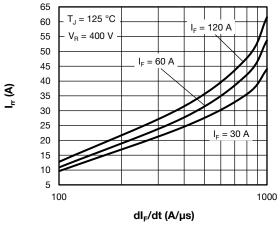


Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

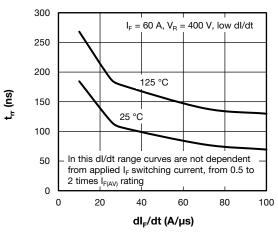


Fig. 10 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

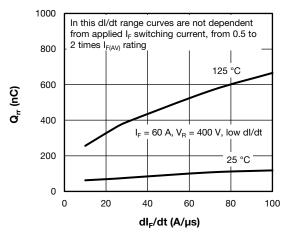


Fig. 11 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

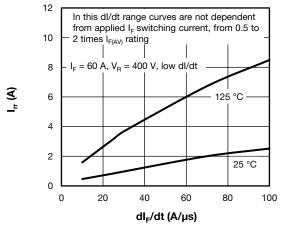


Fig. 12 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

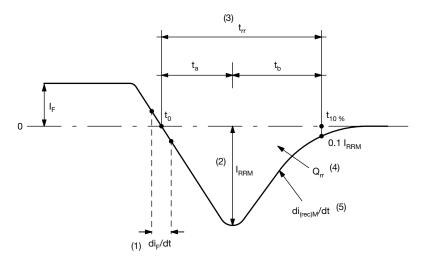


Fig. 13 - Reverse Recovery Waveform and Definitions

#### Notes

- (1) di<sub>E</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from  $t_0$ , crossing point of negative going  $I_F$ , to point  $t_{10\%}$ , 0.1  $I_{RRM}$
- $^{(4)}$   $\, \overset{\circ}{Q}_{rr}$  area under curve defined by  $t_0$  and  $t_{10}\,\%$

$$Q_{rr} = \int_{t_0}^{\tau_{10} \%} I(t) dt$$

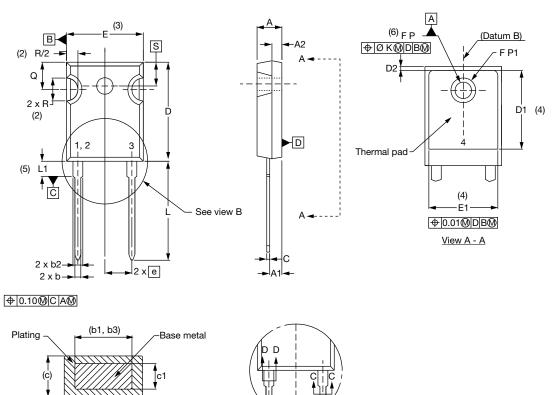
 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5PH6006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95536				
Part marking information	www.vishay.com/doc?95648				

### **TO-247AD 2L**

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	MILLIMETERS		INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	
D2	0.51	1.35	0.020	0.053		

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	254	0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
	•		•	•	

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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